```
On page 5, line 17, please insert -- hole-- after "plug".
      On page 5, line 23, please insert -- hole-- after "plug".
        On page 6, line 1, please insert -- hole-- after "plug".
      On page 6, line 3, please insert -- hole-- after "plug".
        On page 6, line 4, please insert -- hole-- after "plug".
       On page 6, line 6, please insert -- hole-- after "plug".
        On page 6, line 9, please insert -- hole-- after "plug".
        On page 6, line 11, please insert -- hole-- after "plug".
     On page 6, line 12, please insert -- hole-- after "plug".
     On page 6, line 13, please delete "plugs", and insert -- plug hole 20 -- therefor.
      On page 7, line 1, please insert -- hole-- after "plug".
     On page 7, line 4, please insert -- hole-- after "plug".
       On page 7, line 5, please insert -- hole-- after "plug".
       On page 7, line 8, please insert -- hole-- after "plug".
       On page 7, line 9, please delete "formation of the desired", and insert -- filing of the --
therefor.
```

## IN THE CLAIMS:

Please amend the following claims:

- 1. (Twice Amended) A method of filling a feature formed in a dielectric layer, comprising:
  - a) depositing a generally conformal first barrier layer [in] on a bottom and sidewalls of the feature;
    - b) removing the first barrier layer formed on the bottom of the feature;
  - c) [sputter] depositing a second barrier layer [under conditions of a high density plasma] on substantially the bottom of the feature using a directional sputtering technique, wherein the second barrier layer comprises a material selected from a group consisting of Ta, TaN, TaSiN, TiSiN, and combinations thereof; and
    - d) depositing a metal layer in the feature, wherein the metal layer comprises copper.